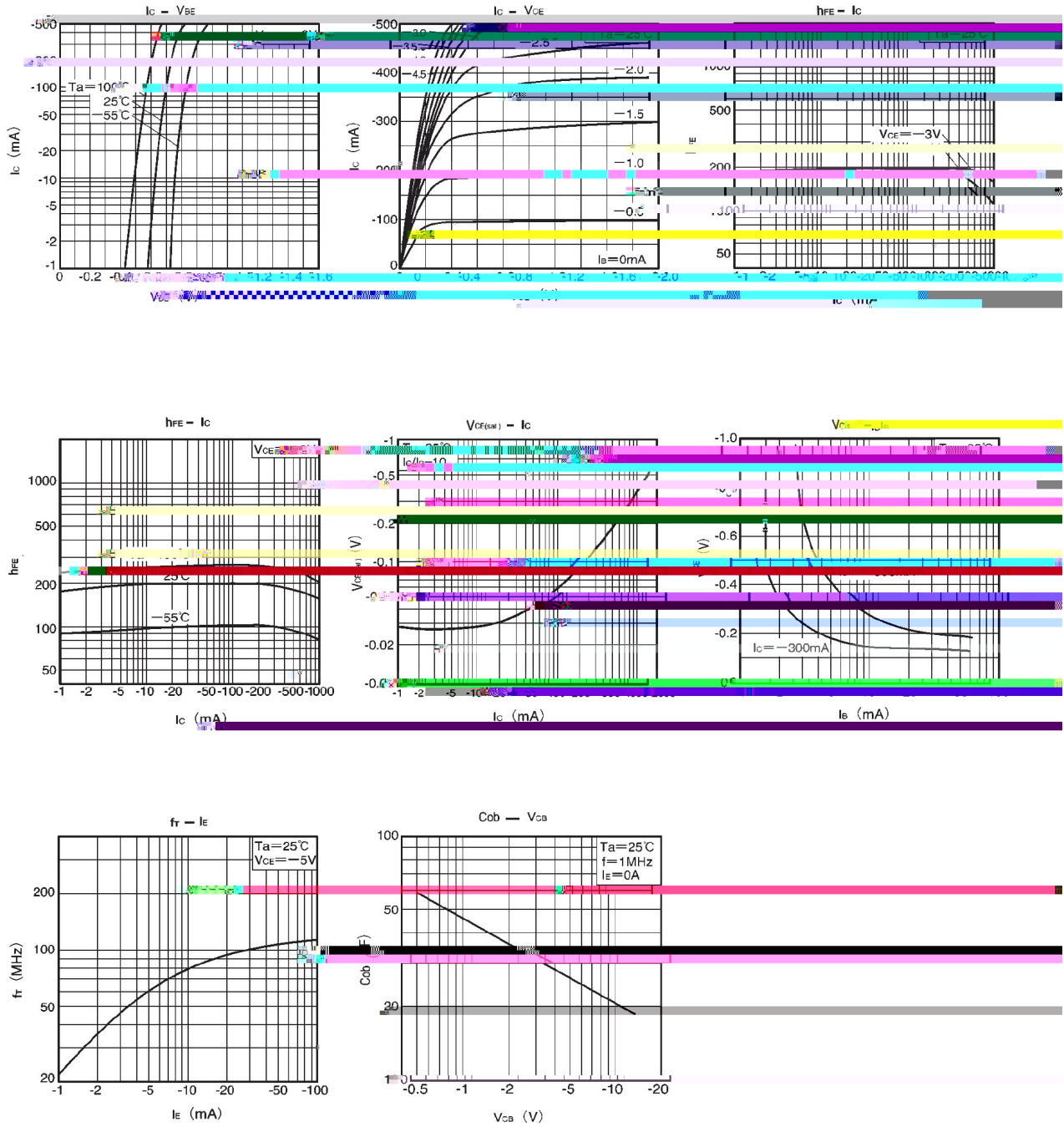


WR0<50 P ММ Ё SQS Æ Ñ ç s ll 1 Silicon PNP transistor in a TO-92LM Plastic Package.

т = я ъ Н/л 5VG4;8; Й ´
Low saturation voltage, complements the 2SD1858.

т = я ъ Н/л 5VG4;8; Й ´
tTT2 -7 4D0-7 17(.00018 Tc.224 (Silicoymbol(w)9ans/TT2 45 71TD-.574(kD001 Tc4.002)9a254(k)TjP Q Ma8)-6Rs

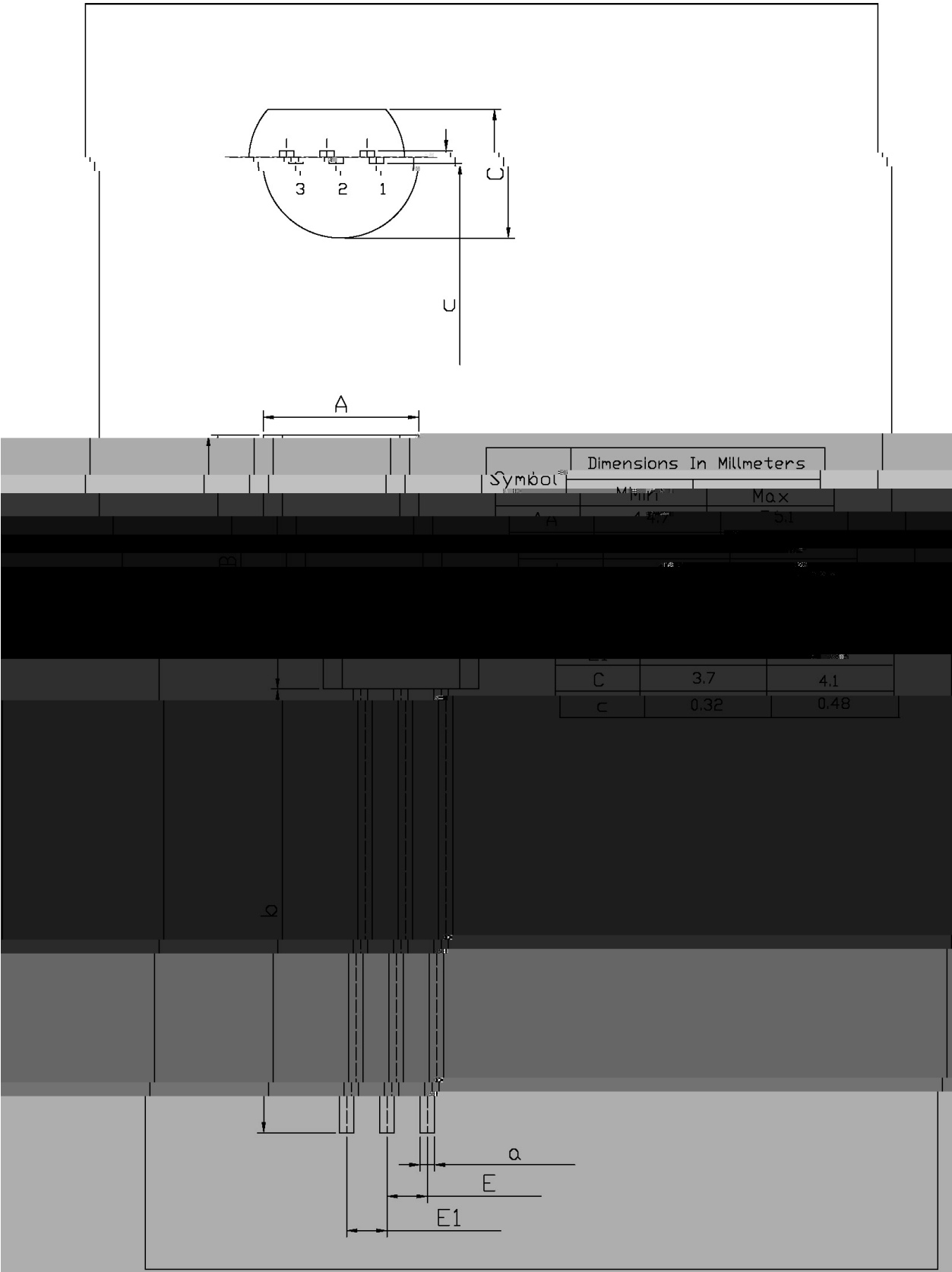
/ Electrical Characteristic Curve



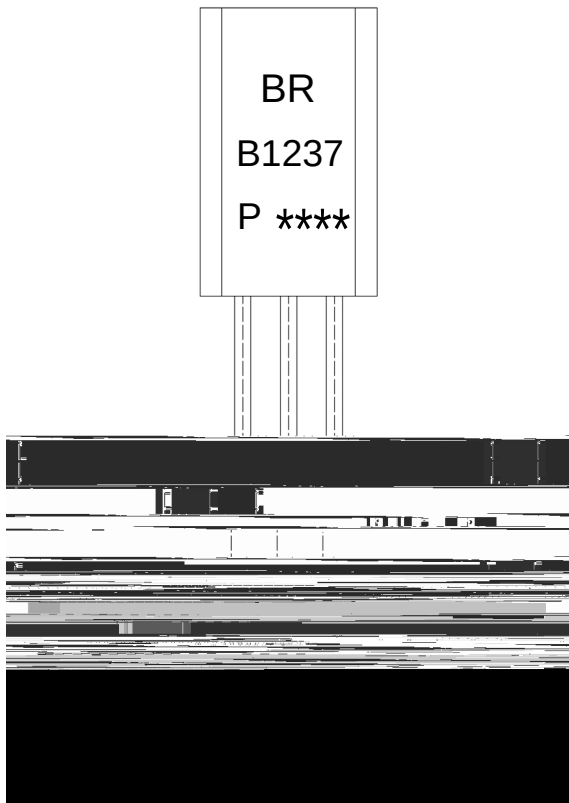
/ Package Dimensions

TO-92LM

Unit: mm



/ Marking Instructions



公司代码	BR
EU:	公司代码
E456: 公司代码	公司代码
S:	公司代码
---- 公司代码	公司代码 公司代码
Note:	
BR:	Company Code.
B1237:	Product Type.
P:	h_{FE} Classifications Symbol
****:	Lot No. Code,code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



б " X

1. 1. Preheating: 25~150 °C, Time: 60~90sec;
2. 2. Peak Temp.: 255 °C, Duration: 5 °C 0.5sec;
3. 3. Cooling Speed: 2~10 °C/sec.

Note:

1. Preheating: 25~150 °C, Time: 60~90sec.
2. Peak Temp.: 255 °C, Duration: 5 °C 0.5sec.
3. Cooling Speed: 2~10 °C/sec.

/ Resistance to Soldering Heat Test Conditions

□ °C 270 ± 5 °C °C 10 ± 1 sec. Temp.: 270 ± 5 Time: 10 ± 1 sec

/ Packaging SPEC.

°C °C °C / BULK

Package Type	Units					Dimension (unit mm3)		
	Units/Bag	Bags/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Bag	Inner Box	Outer Box
TO-92LM	1,000	8	8,000	5	40,000	135×190	237×172×102	560×245×195

°C °C °C / AMMO

Package Type	Units					Dimension (unit mm3)	
	Units/tape	Tape/Inner Box	Rows/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Inner Box	Outer Box
TO-92LM	2,500	1	100	10	25,000	328×230×42	480×346×235 547×407×268

/ Notices